



# Article Controlling I-V Hysteresis in Al/Pt Bilayer Symmetric SQUIDs at Millikelvin Temperatures

Dmitry S. Yakovlev <sup>1</sup>, Ivan A. Nazhestkin <sup>2</sup>, Nidzhat G. Ismailov <sup>3</sup>, Sergei V. Egorov <sup>2,4</sup>, Vladimir N. Antonov <sup>5,6,\*</sup> and Vladimir L. Gurtovoi <sup>2,7</sup>

- <sup>1</sup> Laboratoire de Physique et d'Etude des Matériaux, ESPCI-Paris, PSL Research University, 75005 Paris, France
- <sup>2</sup> Russian Quantum Center, Skolkovo, 143025 Moscow, Russia
- <sup>3</sup> Faculty of Physics, Lomonosov Moscow State University, 119991 Moscow, Russia
- <sup>4</sup> Laboratory of Superconductivity, Institute of Solid State Physics, 142432 Chernogolovka, Russia
- <sup>5</sup> Center for Engineering Physics, Skolkovo Institute of Science and Technology, Bolshoy Boul, 30, 121205 Moscow, Russia
- <sup>5</sup> Physics Department, Royal Holloway University of London, Egham TW20 0EX, UK
- <sup>7</sup> Institute of Microelectronics Technology and High Purity Materials, Russian Academy of Sciences, 142432 Chernogolovka, Russia
- \* Correspondence: v.antonov@rhul.ac.uk

Abstract: We study operation of a superconducting quantum interference devices (SQUIDs) based on a new bilayer material. They can be used for the ultra-sensitive detection of magnetic momentum at temperatures down to milliKelvin range. Typically, thermal origin hysteresis of the symmetric SQUID current-voltage curves limits operating temperatures to T > 0.6Tc. We used a new bilayer material for SQUID fabrication, namely proximity-coupled superconductor/normal-metal (S/N) bilayers (aluminum 25 nm/platinum 5 nm). Because of the 5 nm Pt-layer, Al/Pt devices show nonhysteretic behavior in a broad temperature range from 20 mK to 0.8 K. Furthermore, the Al/Pt bilayer devices demonstrate an order of magnitude lower critical current compared to the Al devices, which decreases the screening parameter ( $\beta_L$ ) and improves the modulation depth of the critical current by magnetic flux. Operation at lower temperatures reduces thermal noise and increases the SQUID magnetic field resolution. Moreover, we expect strong decrease of two-level fluctuators on the surface of aluminum due to Pt-layer oxidation protection and hence significant reduction of the 1/f noise. Optimized geometry of Al/Pt symmetric SQUIDs is promising for the detection of single-electron spin flip.

**Keywords:** symmetric SQUIDs; Al/Pt bilayer; superconductivity; non-hysteretic; millikelvin; Dayem bridge

## 1. Introduction

The new wave of quantum technology aims to use basic principles of quantum mechanics, such as superposition or entanglement. Many of these devices operate at mK temperatures. High-sensitive detectors are key elements in the development of the mentioned technologies.

To obtain the precision sensing of quantum states, superconducting quantum interference devices (SQUIDs) can be used [1,2]. SQUIDs are known as the most sensitive magnetic sensors, theoretically capable of measuring magnetic fields so small as to detect a single electron spin-flip [2], which is useful for a wide range of applications [3]. The operation of SQUIDs is based on measuring the small fraction of the magnetic flux quanta. In recent decades, SQUIDs have been successfully used in scanning probe microscopes with a variety of different modes and designs [4–8]. Ultrasensitive SQUIDS are also used in qubits based on high-anisotropic molecular clusters and magnetic particles with large spins placed in the center of a SQUID loop. In these systems, the ground- and excited-quantum



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**Copyright:** © 2023 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). states are distinguished by a magnetic field; a sensitivity of 10–100  $\mu_B$  is required. Modern dilution refrigerators can provide base temperatures as low as 10 mK for the operation of such systems. Unfortunately, typical SQUIDs have depressed sensitivities at millikelvin temperatures due to hysteresis of current–voltage (I-V) characteristics [9–11]. In addition to the decrease in sensitivity, hysteresis prevents traditional SQUID read-out methods with current biases and increases the measurement times [12,13]. Hysteresis is quite common in many superconducting nano-structured systems, such as the superconductor–insulator–superconductor (SIS), superconductor–normal metal–superconductor (SNS), superconductor–ferromagnetic–superconductor (SFS), nanowire-based Josephson junctions (JJ), and JJs with topological insulators [14–18]. It is important to explain the origin of hysteresis and devise a way to tackle it. In recent decades, understanding the effect has substantially advanced, and several models have been proposed [19,20].

The motivation of our work is to develop the SQUID with suppressed hysteresis of the I-V characteristics down to the millikelvin temperature. An usual approach is to add a resistive shunt parallel to the Josephson junctions [21–23]. It solves the problem, but the shunt resistor takes up a lot of space on a chip. Moreover, it decreases the voltage modulation and, thus, decreases the signal-to-noise ratio of the SQUID-based readout. This can be overcome with techniques based on relaxation oscillations, which add additional noise compared to a classic readout system [24]. In SQUIDS with weak links, the shunt resistors lead to relaxation oscillations, and the resulting performances of such shunted SQUIDs are comparable to those of hysteretic SQUIDs [21]. The other approach is a determination of a critical current with the lock-in method [25], but it is complicated and slow compared to a simple readout. In [26], a bilayer of thick Ti (100 nm) and Au films (23 nm) was proposed to obtain a regime without hysteresis at temperatures up to mK.

As the authors of [27] show, when using materials with  $\rho_s > \rho_n$  (where  $\rho_n$  and  $\rho_s$  are the normal-state resistivity types of normal and superconducting metals, respectively), the critical currents at low temperatures increase in times of low temperatures relative to superconducting films without noble normal metal films, which apparently complicates obtaining the hysteresis-free mode, requiring a thicker film of normal metal [28].

In our work, we use a combination of materials where  $\rho_s \ll \rho_n$ . Aluminum is used as the superconducting layer and platinum as the normal layer. With such a system, the critical current at ultra-low temperatures (down to 10 mK) is reduced and the hysteresis-free regime is preserved. Furthermore, the thin noble metal layer protects the aluminum from oxidation, leading to significant suppression of the formation of amorphous oxide on the aluminum surface and, hence, to a significant reduction in 1/f noise caused by TLS defects [29], which may bring additional advantages in 'nanoscide' operation and a simpler condition to obtain the one-spin flip detection mode. The dominant sources of noise in SQUIDs at low temperatures are the thermal (Johnson–Nyquist) noise at the SQUID and low-frequency 1/f noise from amorphous oxides of superconducting materials (such as aluminum, niobium, and niobium nitride) on SQUID surfaces and metal-substrate interfaces [30–33]. Defects in such oxides allow atoms to tunnel between two states, resulting in the formation of two-level energy states with a wide spectral energy distribution coupled to the operating frequency range of quantum devices. As a result, amorphous oxide two-level fluctuators chaotically absorb energy from operated structures and devices, which increases the quantum detector noise, reduces the coherence time of superconducting quantum bits, and decreases the quality factors of superconducting quantum circuits [34,35].

We report SQUID based on a proximity Al/Pt (S/N) bilayer that does not have hysteresis over a wide range of cryogenic temperatures. The proximity layer pushes down  $T_C$  of the constriction locale of the SQUID loop through the nearness impact and coordinates the ideal parameters with a suppressed hysteresis. Full control over the thickness of the deposition metal allows one to obtain the required critical temperature according to the Martinis equation [36]. A very important direction of the low-noise nanoSQUID realization involves the usage of oxidation-resistant superconductors, such as NbN, TiN, or MoRe [37–41], or protection from oxidation-noble metal-superconductor bilayers in com-

bination with careful substrate preparation before the superconductor deposition. For our target temperature range (approximately 0.01–0.8 K), we picked Al as the superconductor ( $T_c$  for the film is about 1.4 K) and Pt as the normal metal. We chose a superconductor based on the relative ease of depositing high-quality Al films. Additionally, the mesoscopic nature of electronic transport in Al has been the subject of recent intensive study, with Al being the most commonly used material for fabricating qubit circuits [42]. The normal metal, platinum, decreases the critical current and leads to the suppression of the screening parameter  $\beta_L = \frac{2\pi L I_c}{\Phi_0}$  (*L* is the geometric inductance of the SQUID loop), so we have  $\beta_L \ll 1$ , which increases the field sensibility of the SQUID [7].

The suppressed parameter  $\beta_L$  is also helpful when SQUIDs are used as flux-tunable inductors in superconducting resonators. Such systems are indispensable for the research of many types of quantum systems, but a magnetic flux hysteresis in a SQUID with  $\beta_L \gtrsim 1$ , which leads to a premature switch to another resonant frequency, thus significantly reducing the resonator tuning range [43]. In addition, a reduced critical current leads to the increment of a SQUID inductance  $L_S = \Phi_0 / I_C \cos(\pi \Phi / \Phi_0)$ , this can be useful in microwave readout techniques. In application to magnetometry, a resolution of 30 n $\Phi_0 / \sqrt{Hz}$  at 30 mK [44] was achieved.

The method introduced in this work allows for extending the temperature range of a SQUID without any additional limitations, such as increased noise or decreased sensitivity, which are commonly encountered with current approaches. This combination (i.e., of increased sensitivity and a low-temperature working range) paves the way toward achieving a sensitivity approaching one Bohr magneton.

## 2. Results and Discussion

The device was fabricated using a standard planar technique where two constrictions (Dayem bridges) serve as weak links. We used electron beam lithography (EBL) followed by Al (25 nm) or Al (25 nm)/Pt (5 nm) deposition with electron beam evaporation on an undoped Si substrate, which was followed by a lift-off process. The platinum layer suppresses the superconducting order parameter in Al in a temperature range from 20 to 800 mK. Electrical transport measurements were conducted down to 20 mK. Further details are presented in Section 3.

The scanning electron microscopy (SEM) images of our typical fabricated SQUID are presented in Figure 1a. The Josephson junction is a constriction with lateral sizes area =  $50 \times 55$  nm (Figure 1b). The thicknesses of the Al/Pt and Al films were 25/5 and 25 nm, respectively (Figure 1c). The SQUID loop area was  $2 \times 2 \mu m^2$ . The relevant characteristics of both devices are shown in Table 1. The electrical resistivity of a device was  $\rho = \frac{R_N d}{l_2 / W' + 2l_3 / W' + l/2W}$ , where  $l_2$  and  $l_3$  are the length of a quarter of a loop and connecting wire, respectively, W' is the width, and l and w are the junction length and width, respectively. This yielded 35.59  $\Omega$ ·nm for Al SQUID and 40.93  $\Omega$ ·nm for Al/Pt SQUID. The *I–V* curves of the Al/Pt SQUID at 0.02–0.8 K are shown in Figure 1d. The maximum critical current  $I_c = 2.93 \,\mu\text{A}$  was achieved at 20 mK. The curves exhibited non-hysteresis behavior in the range of 0.02—0.800 K. The *I–V* curves of pure Al SQUID are shown in Figure 1e. The critical current at 20 mK is 10 times larger compared to Al/Pt SQUID,  $I_c = 28.4 \,\mu$ A. The *I*–*V* curves exhibit hysteresis behavior in a wide range, from 0.02 to 1.25 K. Figure 1f shows the evolution of critical currents with temperature for both devices. For the Al sample, there is a crossover temperature between hysteresis and non-hysteresis behavior,  $T_H \approx 1.25$  K. Thus, the Al SQUID can be used only in a narrow temperature range, from 1.25 to 1.4 K. The Al/Pt SQUIDs can be used in a much wider temperature range of 0.02–0.8 K, where they exhibit non-hysteresis behavior. It is a consequence of the small screening parameter  $\beta_L$  in the Al/Pt sample because of the proximity effect. Next, we demonstrate the performances of our devices.



**Figure 1.** Josephson transport through planar-thin Al/Pt and Al SQUID operations at various temperatures. (a) Scanning electron microscope picture of the device. The voltage across the SQUID is measured at constant  $I_{bias}$ . (b) An image of constriction of  $50 \times 50$  nm. (c) Two types of films form the SQUID, Al and Al/Pt. (d) The non-hysteresis V(I) characteristics of the Al/Pt S1 SQUID taken at T = 0.02-0.8 K. Al/Pt devices have non-hysteresis behavior at all temperature ranges. (e) The hysteresis behaviors of the Al S2 SQUIDs at different temperatures, T = 0.02-1.4 K. (f) The dependencies of the critical and re-trapping currents as functions of T. Al SQUID hysteresis occurs at  $T < T_H = 1.25$  K.

<b>Table 1</b> . Relevant parameters of the devia
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Sample	$I_c, \mu A$	$R_n^{exp}, \Omega$	W <sup>constriction</sup> , nm	d, nm	L, nm	$\delta H, G$	$A_{eff}$ , $\mu$ m <sup>2</sup>	$T_c, K$	$\rho_n, \Omega \cdot nm$
Al/Pt	2.93	23	$55\pm2$	$30\pm1$	$50\pm10$	5.3	3.8	0.8	40.93
Al	28.4	24	$52\pm2$	$25\pm3$	$50 \pm 10$	4.79	4.3	1.41	35.59

Figure 2 shows the magnetoresistance modulation of the samples taken close to the  $T_c$ , at T = 0.7 K for Al/Pt SQUID and T = 1.35 K for Al SQUID at different bias currents. A magnetic field is applied as normal to the film surface. Periodic oscillations of R of the Al/Pt device are observed for a bias current between 0.5 and 1.4  $\mu$ A (Figure 2a). The period of the oscillations,  $\delta H \approx 5.3$  G, corresponds to the magnetic flux quantum,  $\Phi_0 = h/2e$  through the effective area of the loop. For the Al device, the magnetoresistance oscillations have parabolic shapes with minima at  $\Phi = n\Phi_0$  and maxima (parabolas junctures) at  $\Phi = n\Phi_0/2$  (see Figure 2b). The oscillation amplitudes in the Al/Pt and Al devices have different dependencies on the bias current; see Figure 2c,d. They monotonically decrease in the Al/Pt sample, while in the Al sample, they increase with a sharp jump at 2.67  $\mu$ A followed by a drop to a negligible value after a jump.



**Figure 2.** Comparison of the measured Al/Pt and Al magnetoresistance oscillations. (**a**,**b**) Resistance of Al and Al/Pt samples vs. the applied magnetic field and bias current. (**c**,**d**) The amplitude of the oscillations,  $\Delta R$  vs. bias current defined at low fields.

The measured and modeled magnetoresistance oscillations for the Al/Pt SQUID are presented in Figure 3. The oscillations are typical for SQUIDs [45]. They can be described with the SQUID model for  $I_{\rm C} = 0.629 \ \mu$ A. We obtained a resistance modulation depth  $R \simeq 3\Omega$  for values of the bias current slightly above  $I_{C}$ . A linear drift in the data arising from the temperature instability in a refrigerator was removed. The oscillations for the bilayer Al/Pt sample fit well with the low capacitance SQUID RSJ model [45,46] (Figure 3a) for the vast majority of Dayem bridge devices. The critical current at this temperature was a fit parameter and was used to clarify the value from a I-V curve at a temperature close to critical. The system of differential equations presented in Section 3 describes the dynamics of SQUID, as well as the average SQUID voltage. A system was solved numerically using the Adams method. Some discrepancies in amplitude presumably arise from the inequality between the critical currents of two Dayem bridges. Figure 3b shows changes in the shape of the magnetoresistance curve at different bias currents  $i_b = I_b/I_c$ . Note the periodic behaviors of flux quanta, provided that the SQUID is single-valued. See Section 3 for calculation details. Our measurement results show that non-hysteretic SQUID can be considered as a magnetic flux to the voltage transducer and can be employed as a good magnetic flux detector.

The hysteresis in SQUIDs is usually referred to as the Joule heating effect at the weak link regions [9]. For single-layer Al cases, the large hysteresis appeared when the current exceeded 20  $\mu$ A. At the same time, in Al/Pt bilayer SQUIDs, the hysteresis at this current was not observed. The tolerance to the self-heating effect was improved by the bilayer structure. These facts indicate that the presence of a normal layer, particularly the Pt layer, effectively reduces the heat concentration at the junction area. This method with a normal metal layer used as a thermal shunt has already been used in devices with higher bath temperatures [47,48]. We pioneered the application of a thermal shunt at ultralow temperatures.



**Figure 3.** Magnetoresistance oscillations in Al/Pt SQUID with bias current. (a) Al/Pt sample oscillations are described by the RSJ SQUID model. Blue curve: measured magnetoresistance; red curve: theoretical magnetoresistance. Oscillation period: 4.77 G. (b) Theoretical calculations for voltage modulations of SQUID as functions of the magnetic flux for different values of the bias current. The curves correspond from the bottom to the top to the applied control currents of 0.63, 0.75, 0.92, 1.06, 1.25, and 1.37  $\mu$ A, respectively.

We observed an atypical dependence of the critical current  $I_c$  on the temperature, which cannot be explained within standard theories. In Dayem bridges, suppression of superconductivity can result from the motion of Abrikosov vortices across a junction or the occurrence of phase-slip centers originating from thermal or quantum fluctuations [49,50]. The size of the vortex in the latter case is about  $\sim \xi$ . In thin films, Al is in the dirty limit and  $\xi_{Al} = \sqrt{\frac{\hbar D}{2\pi k_B T_C}}$  [51], where D is a diffusion constant. Using the Einstein relation  $\sigma = e^2 ND$ , where  $N = 2.4 \times 10^{28} \text{ eV}^{-1} \text{ cm}^{-1}$  is the density of Al states at the Fermi energy [52,53], one can find D = 7.18 and  $\xi_{Al} = 78.7$  nm, which is more than a junction width of 55 nm. Consequently, the specificity of a critical current dependence can be explained by phase-slip centers. At these points, quantum fluctuations produce stochastic variations of the critical current around an average value. A resulting stable normal or superconductive state depends on the state times, which in turn are determined by junction voltage.

## 3. Methods

#### 3.1. E-Beam Lithography and Deposition

A high-resolution electron beam (e-beam) lithography system was exploited for nanopatterning the films. We used poly(methyl methacrylate) (PMMA) as a positive tone resist. To pattern the masks, we used a JEOL 7001f SEM equipped with an EBL module. The necessary dose in our case was 400  $\mu$ C/cm<sup>2</sup>. We used a mixture of MIBK 1 part and IPA 3 parts to develop the e-beam pattern and clean IPA as a stopper. After development, the mask was dried in N<sub>2</sub> gas.

We used the e-beam evaporation technique through a tough mask and the controlled lift-off process. Fabrication consisted of three steps in one vacuum cycle e-beam evaporation at room temperature. First, etching was done by inflating a low flow of pure Argon plasma into the chamber; this involved the Ar pressure  $4 \times 10^{-3}$ , RF power  $P_{RF} = 200$  W,  $V_{DC} = 250$  V, Time = 10 s, and flow = 4 SCCM. Second, the e-beam evaporation of 25 nm aluminum was performed with a base pressure of  $4.2 \times 10^{-3}$  mBar, deposition rate of 0.5 nm/s, and emission current of 157 mA. We used 99.99% purity Al granules. Finally, 5 nm of platinum evaporation (by the e-beam) was produced with a base pressure of  $7.8 \times 10^{-8}$  mBar, a deposition rate of 0.2 nm/s, and an emission current of 196 mA. Be-

cause this growth was not performed on an epitaxial substrate, X-ray diffraction (XRD) measurements characterized the films as polycrystalline.

#### 3.2. Measurement Details

All DC measurements were made in a dilution refrigerator (BlueFors LD-250). A copper sample holder carefully shielded from magnetic fields with the Amumetal shield (hydrogen annealed for maximum permeability) and from non-equilibrium photons enabled the four-point (contact) method using separate twisted pairs for current and voltage contacts. DC measurements were performed with symmetric current biasing of a sample. To minimize the switching noise of the analog-to-digital conversion (ADC) card inputs, the Leonardo II 24-bit ADC card measures signals—not from the samples directly but from the outputs of the current (AD8220) and voltage (AD8421) instrumentation amplifiers (IAs). The voltage noise density of the amplifier was  $3 nV / \sqrt{Hz}$ . To improve the accuracy of the current signal, the voltage drop in the measured structure was removed from the current signal. All electrical inputs and outputs from the cryostat go through pi filters (C = 2.5 nF), and then through a two-stage symmetric low-pass RC filter (R = 1 k $\Omega$ , C = 100 nF, cutoff frequency of 1.7 kHz). At the 100 mK flange, a compact silver-epoxy microwave filter made of twelve 1.6 m long twisted pairs (TP filter) is used. This filter is analogous to the silver-epoxy microwave filters and 'thermalizers' used for millikelvin experiments [54]. The TP filter is located at the input to the sample holder on the mixing chamber flange. This filter provides significant attenuation of frequencies that cannot be suppressed with RC filters (up to 20 GHz). The measuring scheme is described in detail in [55].

### 3.3. Magnetoresistance Oscillation Fitting

Magnetoresistance oscillations in Al/Pt SQUID were modeled using the modified resistively shunted junction model (RSJ model) [45,46]. Equations for the junction current in this approach can be written as:

$$\begin{cases} I_{S_{1,2}} = I_c \sin \varphi_{1,2}, \\ I_{D_{1,2}} = C_J \frac{dV_{1,2}}{dt}, \\ I_{R_{1,2}} = \frac{V_{1,2}}{R_J}, \\ I_{1,2} = I_{S_{1,2}} + I_{D_{1,2}} + I_{R_{1,2}}, \end{cases}$$

where  $C_J$  and  $R_J$  are the capacitance and resistance of each junction, and  $I_C$  is a junction critical current. Using the Josephson relation  $V = \frac{\hbar}{2e}\dot{\phi}$ , the considered current can be written as:

$$I_{1,2} = \frac{\hbar C_J}{2e} \frac{d^2 \varphi_{1,2}}{dt^2} + \frac{\hbar}{2eR_J} \frac{d\varphi_{1,2}}{dt} + I_c \sin \varphi_{1,2}$$

One can neglect the capacitive term because of the small capacitance of Dayem bridges:

$$I_{1,2} = \frac{\hbar}{2eR_J} \frac{d\varphi_{1,2}}{dt} + I_c \sin \varphi_{1,2}$$

For the whole SQUID, one can write:

$$\begin{cases} I_{\text{bias}} = I_1 + I_2 \\ \Phi = \Phi_e - L_1 I_1 + L_2 I_2 \end{cases}$$

where  $I_{\text{bias}}$  is the SQUID bias current,  $I_1$  and  $I_2$  are the currents over the SQUID arms,  $L_1$  and  $L_2$  are the inductance of the SQUID arms, and  $\Phi_e$  is the external magnetic flux applied to the SQUID. After the substitution of junction currents, this system looks as follows:

$$\begin{cases} I_{\text{bias}} = I_1 + I_2\\ \Phi = \Phi_e - L_1 \left(\frac{\hbar\omega_c}{2eR_J}\frac{d\varphi_1}{d\tau} + I_c\sin\varphi_1\right) + L_2 \left(\frac{\hbar\omega_c}{2eR_J}\frac{d\varphi_2}{d\tau} + I_c\sin\varphi_2\right) \end{cases}$$

Substitutions  $t = \frac{\tau}{\omega_c}$  (where  $\omega_c = \frac{2e}{\hbar} I_c R_J$ ),  $\beta_{L_1} = \frac{L_1}{L_J}$ ,  $\beta_{L_2} = \frac{L_2}{L_J}$  (where  $L_J = \frac{\hbar}{2eI_c}$ ), make these equations dimensionless, i.e.:

$$\begin{cases} i_{\text{bias}} = \dot{\varphi}_1 + \sin\varphi_1 + \dot{\varphi}_2 + \sin\varphi_2\\ \varphi_1 - \varphi_2 = \varphi_e - \beta_{L_1}(\dot{\varphi}_1 + \sin\varphi_1) + \beta_{L_2}(\dot{\varphi}_2 + \sin\varphi_2) \end{cases}$$

or

$$\begin{cases} \dot{\varphi}_{1} = \frac{\beta_{L_{2}}}{\beta_{L_{1}} + \beta_{L_{2}}} \left( i_{b} - \frac{1}{\beta_{L_{2}}} (\varphi_{1} - \varphi_{2} - \varphi_{e}) \right) - \sin \varphi_{1} \\ \dot{\varphi}_{2} = \frac{\beta_{L_{1}}}{\beta_{L_{1}} + \beta_{L_{2}}} \left( i_{b} + \frac{1}{\beta_{L_{1}}} (\varphi_{1} - \varphi_{2} - \varphi_{e}) \right) - \sin \varphi_{2} \end{cases}$$

The resulting curves are presented in the main text.

#### 4. Conclusions

In summary, we studied the temperature dependence of the critical current and magnetoresistance modulation in two different kinds symmetric SQUIDs with Dayem bridges: (1) based on aluminum and (2) on aluminum-platinum S-N bilayer. We demonstrated non-hysteresis SQUIDs capable of performing continuous read-outs down to the lowest temperature (20 mK). This makes it possible to measure the characteristics of a wide variety of modern quantum systems and decrease the temperature noise. Furthermore, the normal metal layer added to the SQUID reduces its critical current, which increases a field sensibility of a SQUID and provides an opportunity for novel applications. The potential of S-N symmetric bilayer SQUIDs to work in a continuous way at such low temperatures makes them useful tools for studying the ground-state properties of quantum systems. This design is promising for the plausible construction of a long-desired device with a single Bohr magnetron resolution. More experiments are required to fabricate different SQUIDs with variations in the thicknesses of normal and superconducting metals.

**Author Contributions:** V.L.G. conceived the experiment. D.S.Y. and S.V.E. fabricated the samples. D.S.Y., V.L.G. and I.A.N. performed the experiments. D.S.Y., I.A.N. and N.G.I. analyzed the data. D.S.Y., I.A.N., N.G.I. and V.N.A. wrote the manuscript with input from all authors. All authors equally discussed the results and their implications. All authors have read and agreed to the published version of the manuscript.

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